

# LOW-VOLTAGE 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

## IDT74CBTLVR3862 PRELIMINARY

## **FEATURES**:

- · Isolation Under Power-Off Conditions
- · Over-voltage tolerant
- · Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, normal range
- ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)
- · Available in SSOP, QSOP, and TSSOP packages

## **APPLICATIONS:**

· 3.3V High Speed Bus Switching and Bus Isolation

## **DESCRIPTION:**

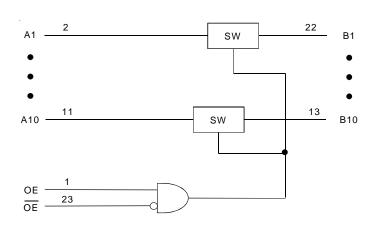
The CBTLVR3862 is a ten bit high-speed bus switch. It adds an internal series resistor with each switch to reduce reflection noise in high-speed applications. When closed, the switch acts as a source (series) termination for the driver connected to it.

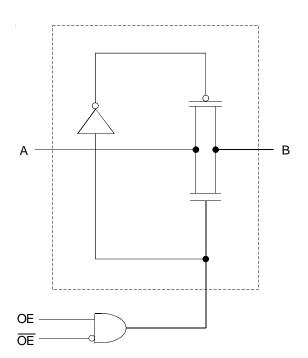
The device is organized as one 10-bit bus switch. The switches are controlled by independent active-low enable  $(\overline{OE})$  and active-high enable  $(\overline{OE})$  controls.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver, and OE should be tied to GND.

### **FUNCTIONAL BLOCK DIAGRAM**

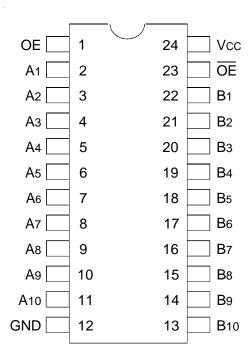
# SIMPLIFIED SCHEMATIC, EACH SWITCH





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### **PIN CONFIGURATION**



SSOP/ QSOP/ TSSOP TOP VIEW

## ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max.	Unit
Vcc	Supply Voltage Range	-0.5 to 4.6	V
Vı	Input Voltage Range	-0.5 to 4.6	V
	Continuous Channel Current	128	mA
lık	Input Clamp Current, VI/O < 0	<b>–</b> 50	mA
Tstg	Storage Temperature Range	-65 to +150	°C

#### NOTE:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
permanent damage to the device. This is a stress rating only and functional operation
of the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect reliability.

## FUNCTION TABLE(1)

Inputs			
OE	ŌĒ	Function	
L	L	Disconnect	
L	Н	Disconnect	
Н	L	A Port = B Port	
Н	Н	Disconnect	

#### NOTE:

1. H = HIGH Voltage Level L = LOW Voltage Level

# OPERATING CHARACTERISTICS(1)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
Vih	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	_	V
		Vcc = 2.7V to 3.6V	2	_	
VIL	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	_	0.7	V
		Vcc = 2.7V to 3.6V	_	0.8	
TA	Operating Free-Air Temperature		-40	+85	°C

#### NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition:  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ 

Symbol	Parameter	Test Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vik	Control Inputs, Data I/O	VCC = 3V, $II = -18mA$		_	_	-1.2	V
lı	Control Inputs	Vcc = 3.6V, VI = Vcc or GND	)	_	_	±1	μA
loz	Data I/O	Vcc = 3.6V, Vo = 0V or 3.6V	switch disabled	_	_	5	μA
loff		Vcc = 0V, VI or Vo = 0V or 3	.6V	_	_	10	μA
Icc		Vcc = 3.6V, lo = 0, VI = Vcc	or GND	_	_	10	μA
$\Delta$ lcc <sup>(2)</sup>	Control Inputs	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		_	_	300	μA
Сі	Control Inputs	Vi = 3V or 0		_	4	_	pF
CIO(OFF)		$Vo = 3V \text{ or } 0, \overline{OE} = Vcc, OE = Vcc$		_	8	_	pF
	Vcc = 2.3V	VI = 0	Io = 64mA	_	30	47	
	Typ. at Vcc = 2.5V		Io = 24mA	_	30	47	
Ron <sup>(3)</sup>		VI = 1.7V	Io = 15mA	_	36	80	Ω
		VI = 0	Io = 64mA	_	30	42	
	Vcc = 3V		Io = 24mA	_	30	42	
		Vi = 2.4V	Io = 15mA	_	32	47	

#### NOTES:

- 1. Typical values are at 3.3V, +25°C ambient.
- 2. The increase in supply current is attributable to each input that is at the specified voltage level rather than Vcc or GND.
- 3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

# **SWITCHING CHARACTERISTICS**

		$Vcc = 2.5V \pm 0.2V$		$Vcc = 3.3V \pm 0.3V$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
t <sub>PD</sub> <sup>(1)</sup>	Propagation Delay	_	0.9	_	1.5	ns
	A to B or B to A					
ten	Output Enable Time	1	6	1	5.3	ns
	OE to A or B					
tois	Output DisableTime	1	5.5	1	5.5	ns
	OE to A or B					
ten	Output Enable Time	1	6	1	5.3	ns
	OE to A or B					
tois	Output DisableTime	1	5.5	1	6	ns
	OE to A or B					

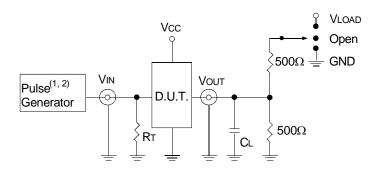
#### NOTE:

<sup>1.</sup> The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

#### TEST CIRCUITS AND WAVEFORMS

## **TEST CONDITIONS**

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc <sup>(2)</sup> = 2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
VIH	3	Vcc	V
VT	1.5	Vcc / 2	V
VLZ	300	150	mV
VHZ	300	150	mV
CL	50	30	pF



Test Circuits for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

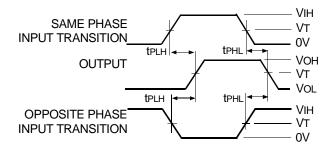
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

#### NOTES:

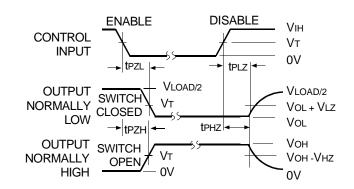
- 1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tr  $\leq$  2.5ns; tr  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

#### **SWITCH POSITION**

Test	Switch
tplz/tpzl	Vload
tpHz/tpzH	GND
tpo	Open



#### **Propagation Delay**

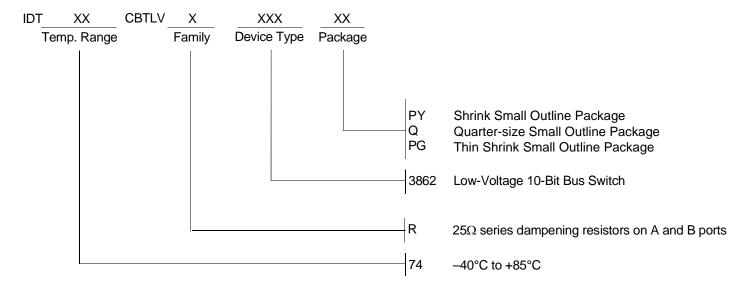


#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

#### **Enable and Disable Times**

## ORDERING INFORMATION





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